

Product data sheet

### 1. General description

Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package

### 2. Features and benefits

- Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

### 3. Applications

- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

### 4. Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage			-	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 78 °C; square-wave pulse; <u>Fig. 1</u> ; <u>Fig. 2</u>		-	-	10	A
Static characte	eristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 A; T <sub>j</sub> = 150 °C; <u>Fig. 4</u>		-	1.4	1.8	V
Dynamic characteristics							
t <sub>rr</sub>	reverse recovery time	$I_F$ = 10 A; $V_R$ = 400 V; $dI_F/dt$ = 500 A/ µs; $T_j$ = 25 °C; <u>Fig. 6</u>		-	19	-	ns





# 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	K A
2	А	anode	$2 \circ 4$	001aaa020
mb	mb	mounting base; connected to cathode	C C C C C C C C C C C C C C C C C C C	

# 6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BYC10-600	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59			

## 7. Limiting values

#### Table 4. Limiting values

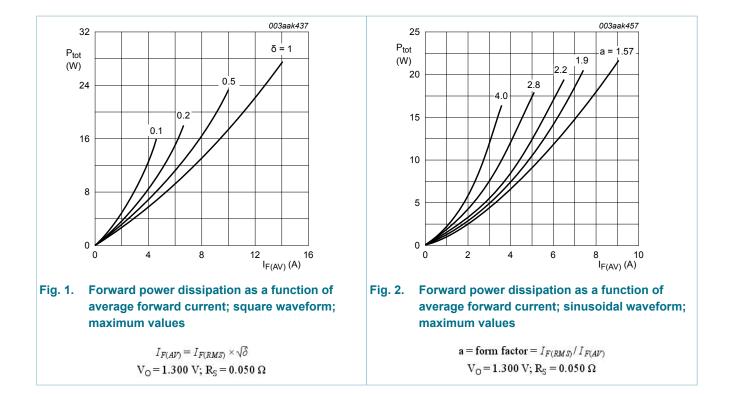
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	600	V
V <sub>RWM</sub>	crest working reverse voltage		-	600	V
V <sub>R</sub>	reverse voltage	T <sub>mb</sub> ≤ 114 °C	-	500	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 78 °C; square-wave pulse; <u>Fig. 1</u> ; Fig. 2	-	10	A
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 78 °C; square-wave pulse	-	20	A
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	65	A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	71	A
T <sub>stg</sub>	storage temperature		-40	150	°C
Тj	junction temperature		-	150	°C

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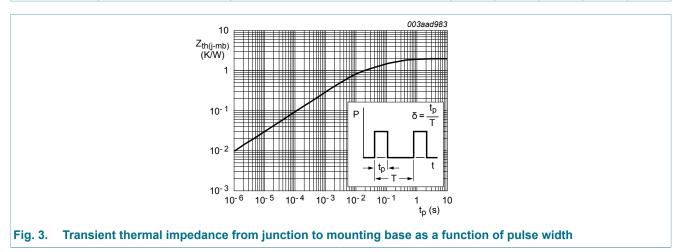
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#### Hyperfast power diode



### 8. Thermal characteristics

#### Table 5. **Thermal characteristics** Symbol Parameter Conditions Min Max Unit Тур thermal resistance K/W Fig. 3 2 \_ R<sub>th(j-mb)</sub> \_ from junction to mounting base thermal resistance in free air K/W 60 \_ R<sub>th(j-a)</sub> \_ from junction to ambient free air



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Hyperfast power diode

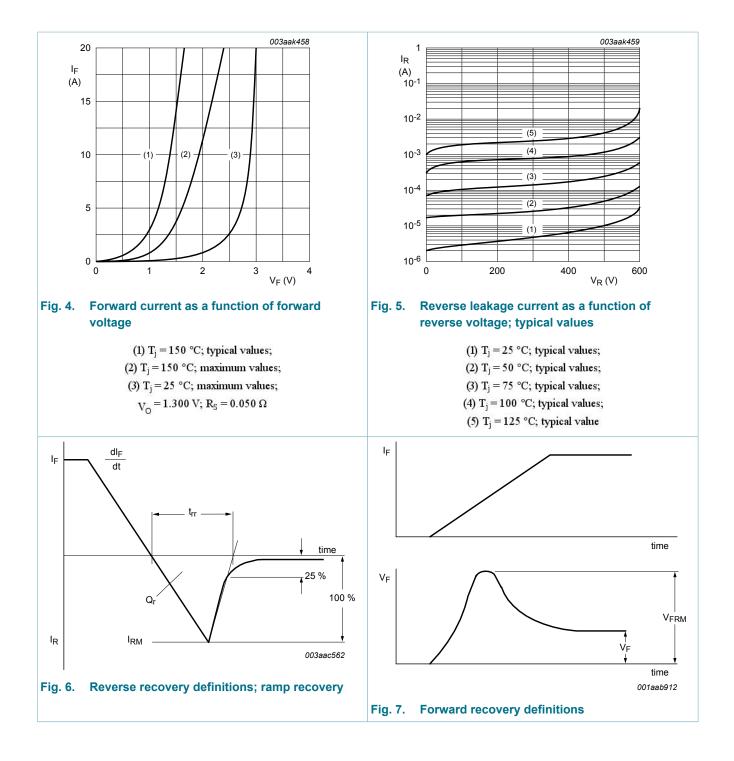
### 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static char	acteristics	· · · · · ·				
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	2	2.9	V
		I <sub>F</sub> = 10 A; T <sub>j</sub> = 150 °C; <u>Fig. 4</u>	-	1.4	1.8	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 150 °C; <u>Fig. 4</u>	-	1.7	2.3	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	9	200	μA
		V <sub>R</sub> = 500 V; T <sub>j</sub> = 100 °C; <u>Fig. 5</u>	-	1.1	3	mA
Dynamic cl	haracteristics	· · · ·	I			
t <sub>rr</sub>	reverse recovery time	I <sub>F</sub> = 1 A; V <sub>R</sub> = 30 V; dI <sub>F</sub> /dt = 50 A/μs; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	35	55	ns
		$I_F$ = 10 A; $V_R$ = 400 V; $dI_F/dt$ = 500 A/ µs; $T_j$ = 25 °C; <u>Fig. 6</u>	-	19	-	ns
		I <sub>F</sub> = 10 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/ μs; T <sub>j</sub> = 100 °C; <u>Fig. 6</u>	-	32	40	ns
I <sub>RM</sub>	peak reverse recovery current	I <sub>F</sub> = 10 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 100 A/ μs; T <sub>j</sub> = 125 °C; <u>Fig. 6</u>	-	3	7.5	A
		I <sub>F</sub> = 10 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/ μs; T <sub>j</sub> = 125 °C; <u>Fig. 6</u>	-	9.5	12	A
V <sub>FRM</sub>	forward recovery voltage	I <sub>F</sub> = 10 A; dI <sub>F</sub> /dt = 100 A/μs; T <sub>j</sub> = 25 °C; Fig. 7	-	8	11	V

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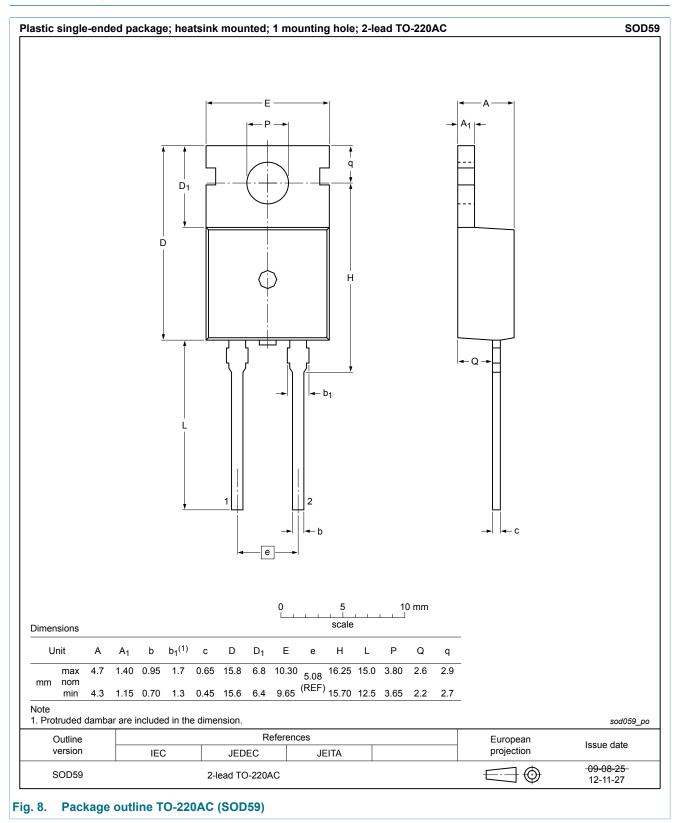
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Hyperfast power diode

### **10. Package outline**



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### 11. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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